

CMS3401T-HF

P-Channel
RoHS Device
Halogen Free



Features

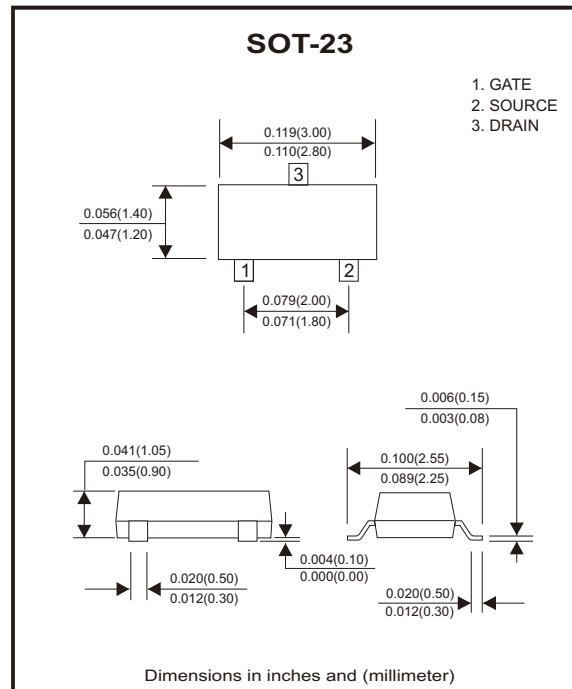
- $V_{DS} = -30V$, $I_D = -4.2A$
- $R_{DS(ON)} < 90m\Omega$ @ $V_{GS} = -2.5V$
- $R_{DS(ON)} < 75m\Omega$ @ $V_{GS} = -4.5V$
- $R_{DS(ON)} < 55m\Omega$ @ $V_{GS} = -10V$
- High power and current handling capability.
- Lead free product is acquired.
- Surface mount package.

Mechanical data

- Case: SOT-23, molded plastic.
- Mounting position: Any.

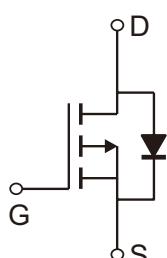
Description

The CMS3401T uses advanced trench technology to provide excellent $R_{DS(ON)}$, low gate charge and operation with gate voltages as low as 2.5V. This device is suitable for use as a load switch or in PWM applications.



Circuit Diagram

- G : Gate
- S : Source
- D : Drain



Application

- PWM applications
- Load switch
- Power management

Absolute Maximum Ratings ($T_A=25^\circ C$ unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-source voltage	V_{DS}	-30	V
Gate-source voltage	V_{GS}	± 12	V
Drain current-continuous	I_D	-4.2	A
Drain current-pulsed (Note 1)	I_{DM}	-30	A
Maximum power dissipation	P_D	1.2	W
Operating junction and storage temperature range	T_J, T_{STG}	-55 to 150	°C

Thermal Characteristic

Thermal resistance, junction-to-ambient (Note 2)	$R_{\theta JA}$	104	°C/W
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Electrical Characteristics ($T_A=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Off Characteristics						
Drain-source breakdown voltage	BV_{DSS}	$V_{\text{GS}} = 0\text{V}, I_{\text{D}} = -250\mu\text{A}$	-30			V
Zero gate voltage drain current	$I_{\text{DS}}^{\text{SS}}$	$V_{\text{DS}} = -24\text{V}, V_{\text{GS}} = 0\text{V}$			-1	μA
Gate-body leakage current	I_{GSS}	$V_{\text{DS}} = \pm 10\text{V}, V_{\text{GS}} = 0\text{V}$			± 100	nA
On Characteristics (Note 3)						
Gate threshold voltage	$V_{\text{GS}(\text{th})}$	$V_{\text{DS}} = V_{\text{GS}}, I_{\text{D}} = -250\mu\text{A}$	-0.7	-1	-1.3	V
Drain-source on-state resistance	$V_{\text{DS}(\text{ON})}$	$V_{\text{GS}} = -10\text{V}, I_{\text{D}} = -4.2\text{A}$		48	55	$\text{m}\Omega$
		$V_{\text{GS}} = -4.5\text{V}, I_{\text{D}} = -4\text{A}$		56	75	
		$V_{\text{GS}} = -2.5\text{V}, I_{\text{D}} = -1\text{A}$		72	90	
Forward transconductance	g_{FS}	$V_{\text{DS}} = -5\text{V}, I_{\text{D}} = -4.2\text{A}$		10		S
Dynamic Characteristics (Note 4)						
Input capacitance	C_{iss}	$V_{\text{DS}} = -15\text{V}, V_{\text{GS}} = 0\text{V}, f = 1\text{MHz}$		880		pF
Output capacitance	C_{oss}			105		
Reverse transfer capacitance	C_{rss}			65		
Switching Characteristics (Note 4)						
Turn-on delay time	$t_{\text{d}(\text{on})}$	$V_{\text{DD}} = -15\text{V}, I_{\text{D}} = -4.2\text{A}$ $V_{\text{GS}} = -10\text{V}, R_{\text{GEN}} = 6\Omega$		7		nS
Turn-on rise time	t_{r}			3		
Turn-off delay time	$t_{\text{d}(\text{off})}$			30		
Turn-off rise time	t_{f}			12		
Total gate charge	Q_{g}	$V_{\text{DS}} = -15\text{V}, I_{\text{D}} = -4.2\text{A}, V_{\text{GS}} = -4.5\text{V}$		8.5		nC
Gate-source charge	Q_{gs}			1.8		
Gate-drain charge	Q_{gd}			2.7		
Drain-Source Diode Characteristics						
Diode forward voltage (Note 3)	V_{SD}	$V_{\text{GS}} = 0\text{V}, I_{\text{S}} = -4.2\text{A}$			-1.2	V

Notes: 1. Repetitive rating: Pulse width limited by maximum junction temperature.

2. Surface mounted on FR4 board, $t \leq 10\text{sec}$.

3. Pulse test: Pulse width $\leq 300\mu\text{s}$, duty cycle $\leq 2\%$.

4. Guaranteed by design, not subject to production.

MOSFET

Typical Electrical and Thermal Characteristics (CMS3401T-HF)

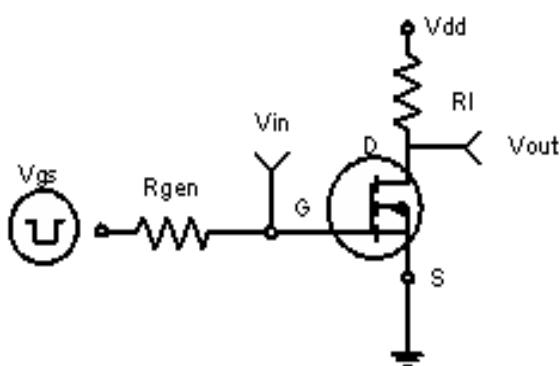


Figure 1:Switching Test Circuit

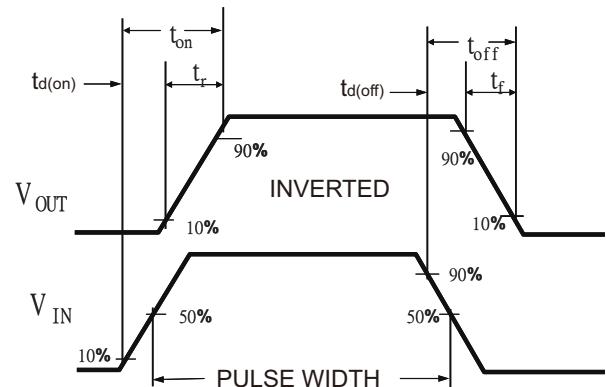
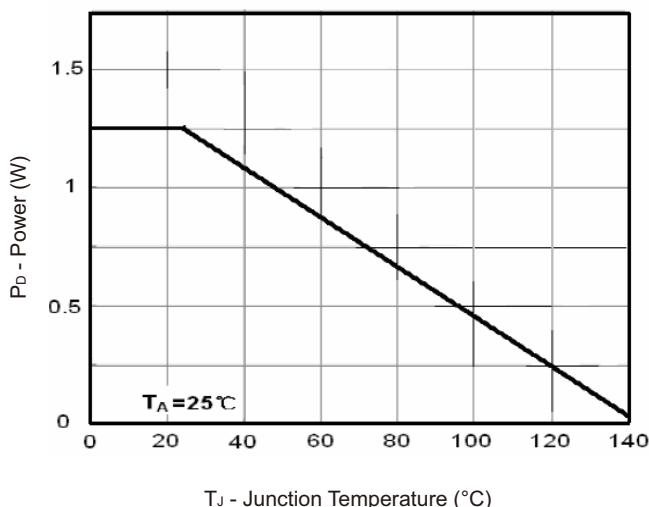
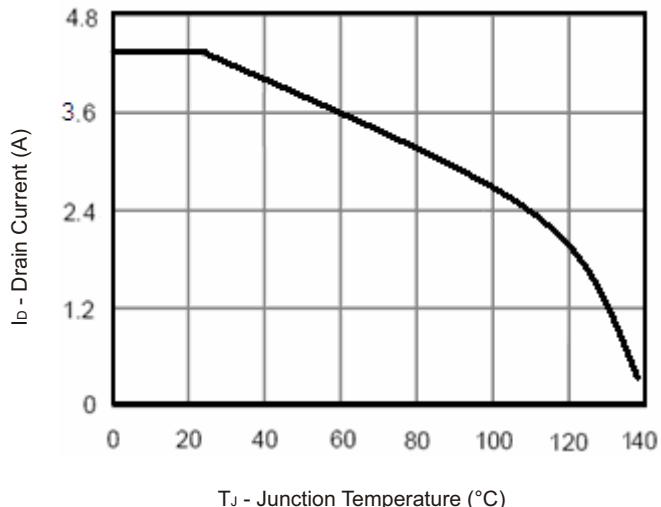


Figure 2:Switching Waveforms



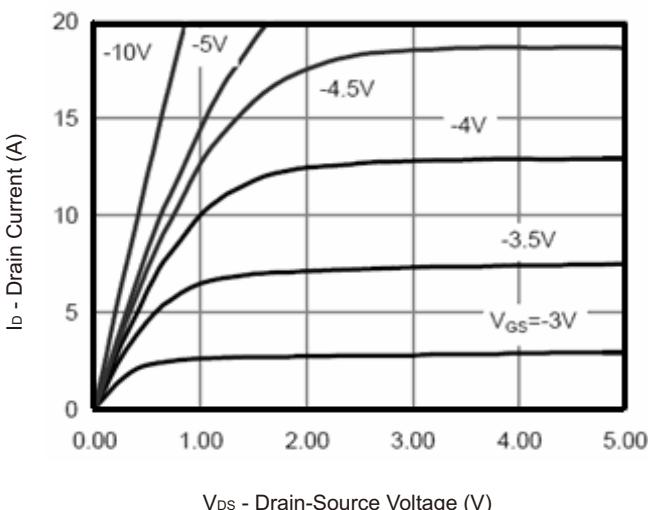
T_J - Junction Temperature (°C)

Figure 3: Power Dissipation



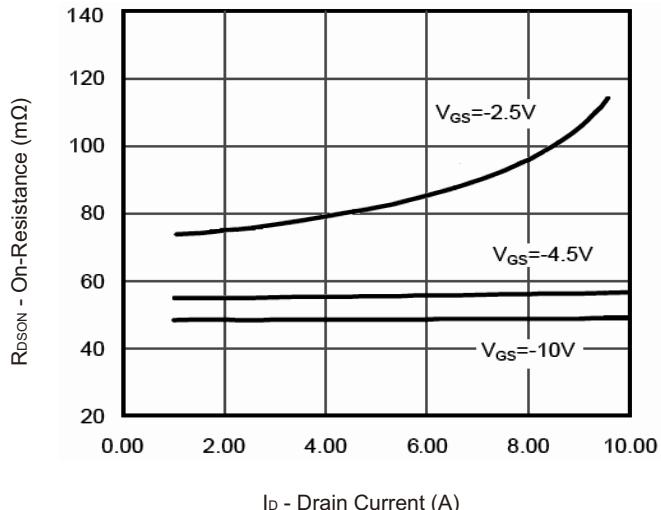
T_J - Junction Temperature (°C)

Figure 4: Drain Current



V_{DS} - Drain-Source Voltage (V)

Figure 5: Output Characteristics



I_D - Drain Current (A)

Figure 6: Drain-source On-Resistance

Typical Electrical and Thermal Characteristics (CMS3401T-HF)

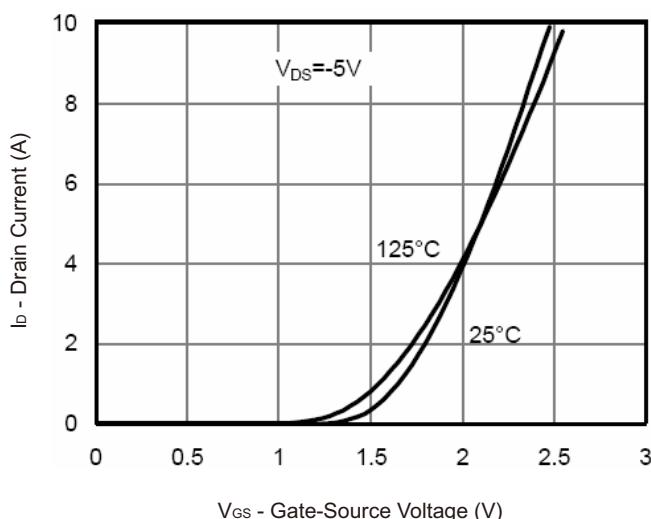


Figure 7: Transfer Characteristics

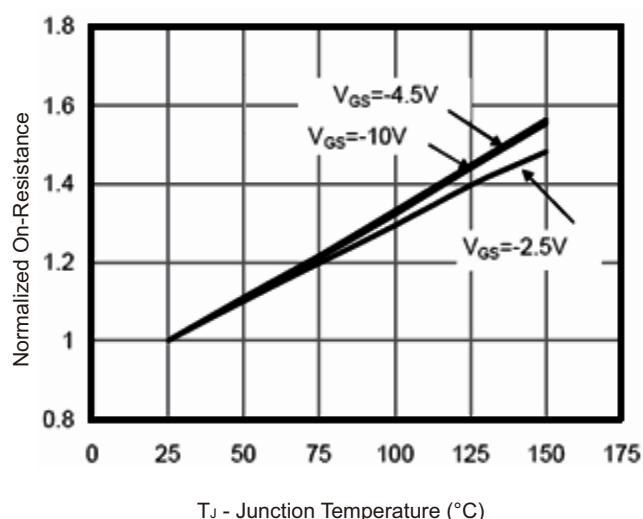


Figure 8: Drain-Source On-Resistance

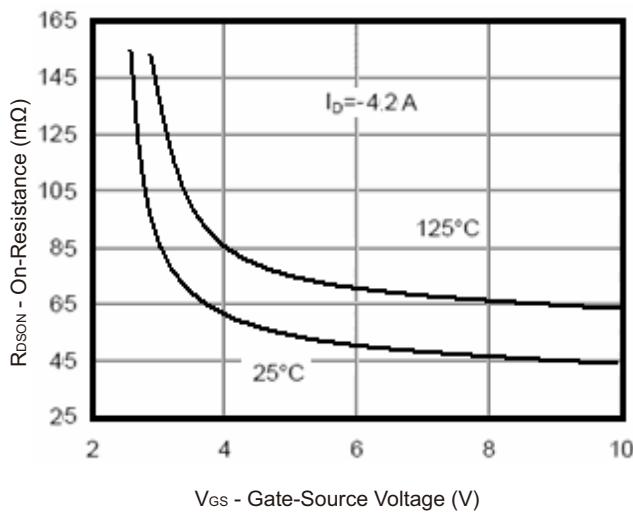


Figure 9: $R_{DS(on)}$ vs V_{GS}

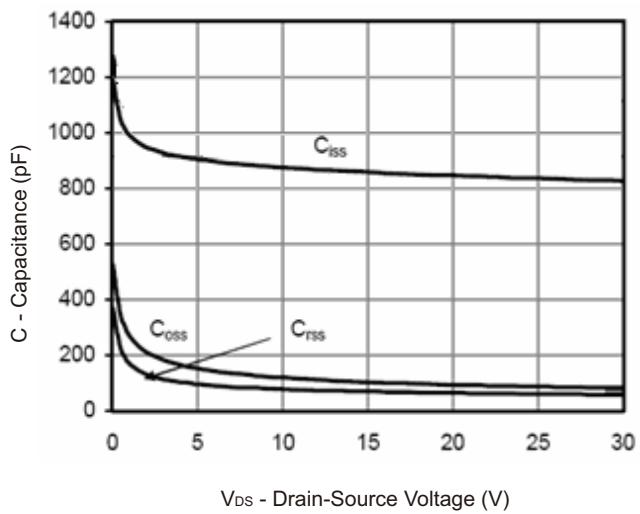


Figure 10: Capacitance vs V_{DS}

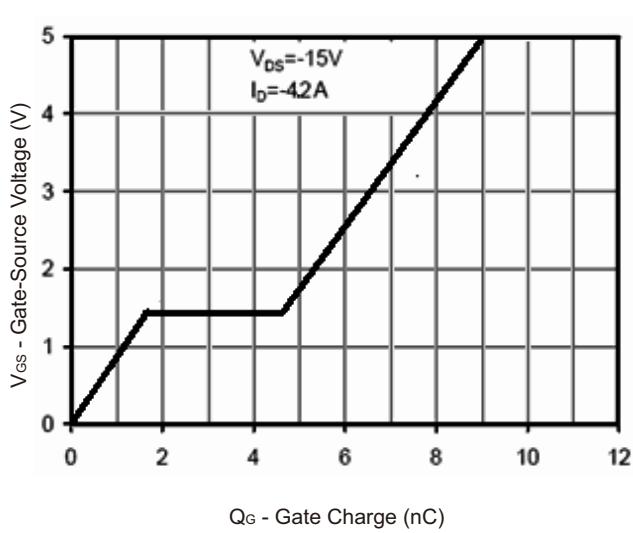


Figure 11: Gate Charge

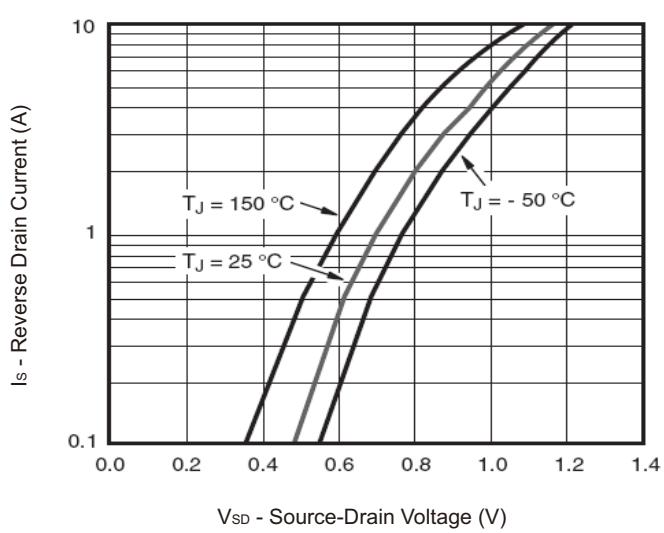


Figure 12: Source-Drain Diode Forward

Typical Electrical and Thermal Characteristics (CMS3401T-HF)

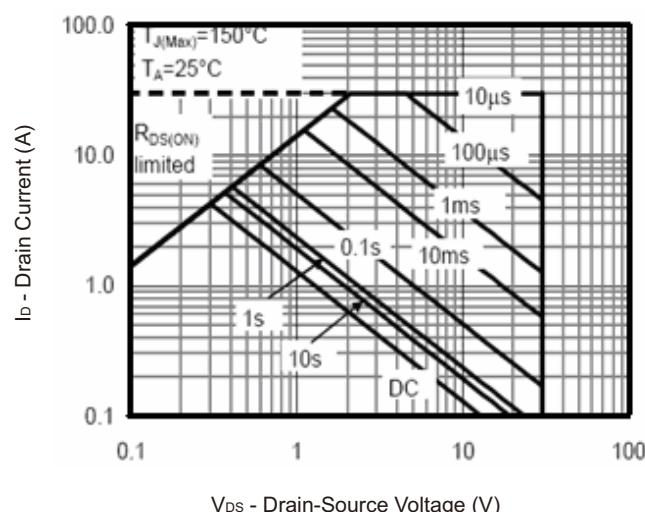


Figure 13:Safe Operation Area

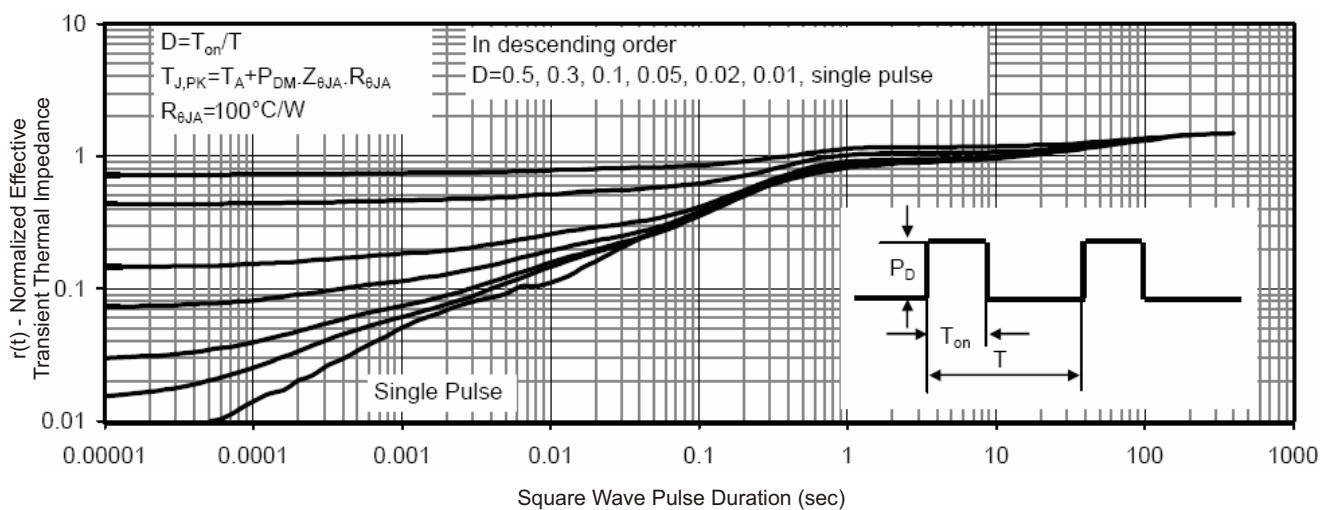
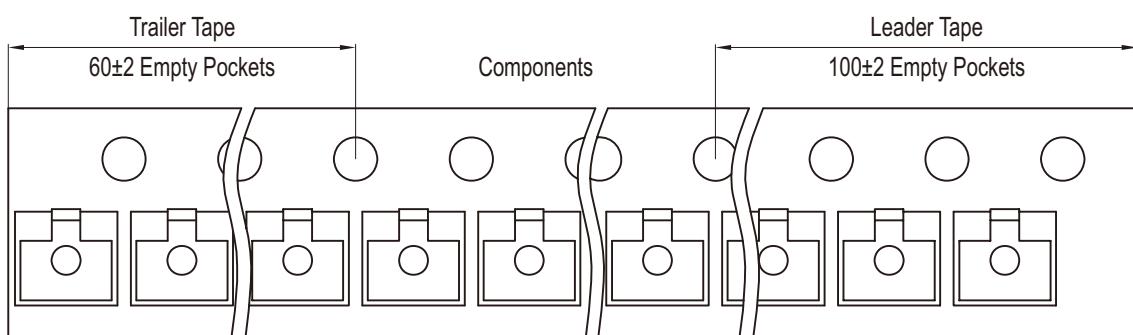
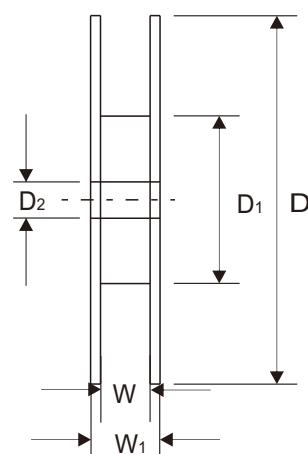
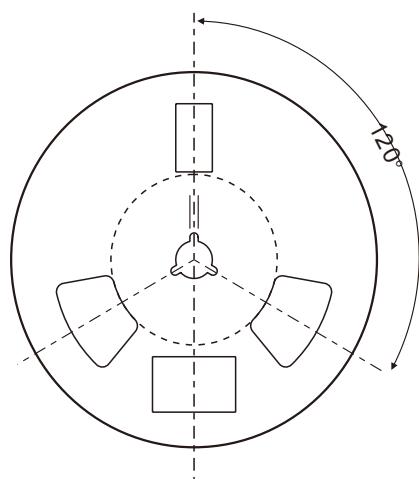
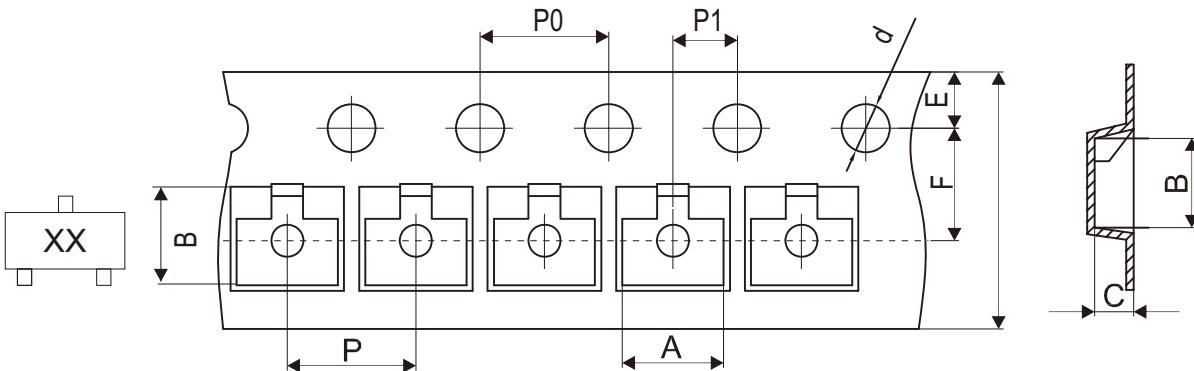


Figure 14:Normalized Maximum Transient Thermal Impedance

Reel Taping Specification

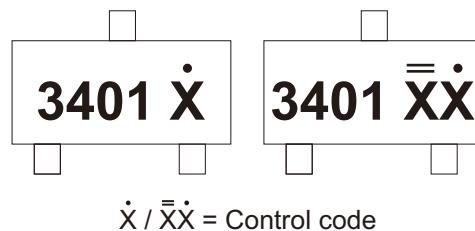


SOT-23	SYMBOL	A	B	C	d	D	D1	D2
(mm)		3.10 ± 0.10	3.20 ± 0.10	1.37 ± 0.10	1.50 ± 0.10	178.00 ± 2.00	54.40 ± 1.00	13.00 ± 1.00
(inch)		0.122 ± 0.004	0.126 ± 0.004	0.054 ± 0.004	0.059 ± 0.004	7.008 ± 0.079	2.142 ± 0.039	0.512 ± 0.039

SOT-23	SYMBOL	E	F	P	P0	P1	W	W1
(mm)		1.75 ± 0.10	3.50 ± 0.10	4.00 ± 0.10	4.00 ± 0.10	2.00 ± 0.10	$8.40 + 1.50 / - 0.50$	12.00 ± 1.50
(inch)		0.069 ± 0.004	0.138 ± 0.004	0.157 ± 0.004	0.157 ± 0.004	0.079 ± 0.004	$0.330 + 0.012 / - 0.004$	0.472 ± 0.039

Marking Code

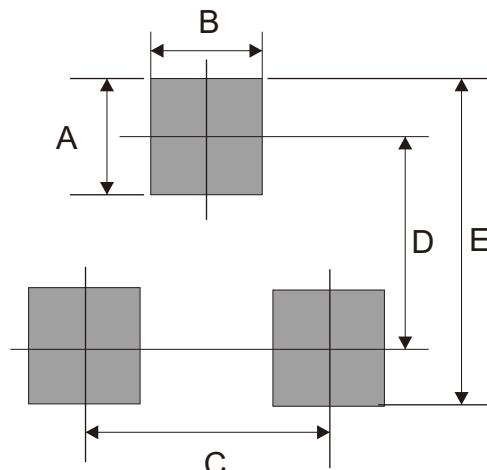
Part Number	Marking Code
CMS3401T-HF	3401



X / XX = Control code

Suggested P.C.B. PAD Layout

SIZE	SOT-23	
	(mm)	(inch)
A	0.80	0.031
B	0.60	0.024
C	2.20	0.087
D	2.37	0.093
E	2.97	0.117



Standard Packaging

Case Type	REEL PACK	
	REEL (pcs)	Reel Size (inch)
SOT-23	3,000	7